

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Atty. Docket

YOURI PONOMAREV

NL 000139

Serial No.

Filed: CONCURRENTLY

SEMICONDUCTOR DEVICE WITH AN INTEGRATED CMOS CIRCUIT WITH MOS TRANSISTORS HAVING SILICON-GERMANIUM ($Si_{1-x}Ge_x$) GATE ELECTRODES, AND METHOD OF MANUFACTURING SAME

Honorable Commissioner of Patents and Trademarks
Washington, D.C. 20231

PRELIMINARY AMENDMENT

Sir:

Prior to calculation of the filing fee and examination, please amend the above-identified application as follows:

IN THE TITLE

Please change the Title to all Capital Letters.

IN THE SPECIFICATION

Page 1, before line 1, insert as a centered heading:

--BACKGROUND OF THE INVENTION--;

Page 2, line 18, insert as a centered heading:

--SUMMARY OF THE INVENTION--;

Page 5, line 4, insert as a centered heading:

--BRIEF DESCRIPTION OF THE DRAWING--;

line 14, insert as a centered heading:

--DESCRIPTION OF THE PREFERRED EMBODIMENTS--;

IN THE CLAIMS

Page 10, before line 1, replace "CLAIMS:" with

--WHAT IS CLAIMED IS:--

Claim 3, line 1, delete "or 2".

Claim 4, line 1, delete "or 3".

Claim 7, line 1, delete "or 6".

Claim 8, line 1, delete "6, or 7,".

IN THE ABSTRACT

Before line 1, delete "ABSTRACT:" and substitute the following

as a centered heading:

--ABSTRACT OF THE DISCLOSURE--;

last line, delete "Fig.13".

REMARKS

The Abstract and Specification have been amended to add headings in accordance with MPEP Section 601. The claims have been amended in order to reformat the claims to delete all multiple dependencies prior to calculation of the filing fee and place the instant application in standard U.S. format.

Entry of this amendment prior to calculating the
filing fee is respectfully requested.

Respectfully submitted,

By 
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